

# UNISONIC TECHNOLOGIES CO., LTD

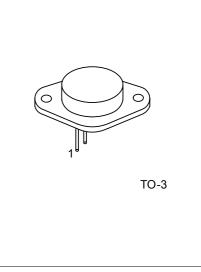
## 2N2955

### PNP SILICON TRANSISTOR

## SILICON PNP TRANSISTORS

#### DESCRIPTION

The UTC 2N2955 is a silicon PNP transistor in TO-3 metal case. It is intended for power switching circuits, series and shunt regulators, output stages and high fidelity amplifiers.



\*Pb-free plating product number:2N2955L

#### ORDERING INFORMATION

| Order Number                 |   | Deekege |     | Pin Assignment                |   |           | Deaking      |  |
|------------------------------|---|---------|-----|-------------------------------|---|-----------|--------------|--|
| Normal                       | Lead Free Plating   | Package |     | 1                             | 2 | 3         | Packing      |  |
| 2N2955-T30-K                 | 2N2955L-T30-K   | TO-     | 3   | E                             | В | С         | Bulk         |  |
| Note: 3: Case                |   |         |     |                               |   |           |              |  |
| 2N2955 <u>L</u> - <u>T30</u> | -K<br>(1)Packing Type<br>(2)Package Type<br>(3)Lead Plating |         | (2) | K: Bulk<br>T30: TC<br>L: Lead |   | lating, B | Blank: Pb/Sn |  |

#### ■ ABSOLUTE MAXIMUM RATINGS ( Ta=25°C , unless otherwise specified )

| PARAMETERS                          | SYMBOL           | RATINGS   | UNITS |
|-------------------------------------|------------------|-----------|-------|
| Collector-Base Voltage              | V <sub>CBO</sub> | 100       | V     |
| Collector-Emitter Voltage           | V <sub>CEO</sub> | 60        | V     |
| Emitter-Base Voltage                | V <sub>EBO</sub> | 7         | V     |
| Collector-Emitter Voltage           | V <sub>CEV</sub> | 70        | V     |
| Collector Current                   | Ι <sub>C</sub>   | 15        | А     |
| Collector Peak Current(1)           | I <sub>CM</sub>  | 15        | А     |
| Base Current                        | I <sub>B</sub>   | 7         | А     |
| Base Peak Current(1)                | I <sub>BM</sub>  | 15        | А     |
| Total Dissipation at Ta=25°C        | PD               | 115       | W     |
| Max. Operating Junction Temperature | TJ               | +200      | °C    |
| Storage Temperature                 | T <sub>STG</sub> | -65 ~ 200 | °C    |

Note Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

#### ■ **ELECTRICAL CHARACTERISTICS** (Ta=25°C, unless otherwise specified)

| ONDITIONS  MIN    /  60    00Ω  70    FF)=1.5V | TYP            | MAX<br>0.7<br>1.0<br>5.0<br>5.0 | UNIT<br>V<br>MA<br>mA<br>mA        |
|--|----------------|---------------------------------|------------------------------------|
| 00Ω 70<br>FF)=1.5V                             |                | 1.0<br>5.0                      | V<br>mA<br>mA                      |
| 00Ω 70<br>FF)=1.5V                             |                | 1.0<br>5.0                      | V<br>mA<br>mA                      |
| <sub>FF)</sub> =1.5V                           |                | 1.0<br>5.0                      | mA<br>mA                           |
|  |                | 1.0<br>5.0                      | mA                                 |
|  |                | 5.0                             |                                    |
|  |                | 5.0                             | mA                                 |
|  |                |                                 |                                    |
|  |                |                                 |                                    |
| 20<br>5  |                | 70                              |                                    |
| \  |                | 1.1<br>3.0                      | V                                  |
|  |                | 1.5                             | V                                  |
|  |                |                                 |                                    |
| s, Non-repetitive 2.87                         |                |                                 | А                                  |
|  |                |                                 |                                    |
| V, f=1MHz 2.5                                  |                |                                 | MHz                                |
| =1kHz 15                                       |                | 120                             |                                    |
|  |                |                                 | kHz                                |
| )'   | 0V, f=1MHz 2.5 | DV, f=1MHz 2.5<br>f=1kHz 15     | DV, f=1MHz  2.5    f=1kHz  15  120 |

Note(1):Pulse Test: PW 300µs, Duty Cycle 2%

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